NSN 5961-00-016-4951

Semiconductor Device Set - Page 1 of 1



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Glass all semiconductor device diode

Overall Length:

0.230 inches all semiconductor device diode and 0.300 inches all semiconductor device diode

Terminal Length:

1.000 inches all semiconductor device diode

Overall Diameter:

0.108 inches all semiconductor device diode and 0.140 inches all semiconductor device diode

Internal Configuration:

Junction contact all semiconductor device diode

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-14 all semiconductor device diode

Internal Junction Configuration:

Pn all semiconductor device diode

Component Function Relationship:

Matched

Component Name And Quantity:

2 semiconductor device diode

Mounting Method:

Terminal all semiconductor device diode

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

225.0 repetitive peak reverse voltage all semiconductor device diode

Current Rating Per Characteristic:

15.00 amperes peak forward surge current and 400.00 milliamperes forward current, average absolute all semiconductor device diode

Terminal Type And Quantity:

2 uninsulated wire lead all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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